Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic
Overall Length:
0.370 inches
Terminal Length:
1.100 inches
Overall Diameter:
0.200 inches
Function For Which Designed:
Transient suppressor
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
78.8 reverse breakdown voltage, dc
Current Rating Per Characteristic:
200.00 amperes peak forward surge current
Power Rating Per Characteristic:
1500.0 watts peak on-state power dissipation
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0